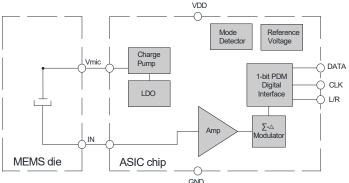


Description

The WD-GFA261-H10F is a small package, high SNR and multimode top port digital MEMS microphone with 1-bit PDM output, consists of a MEMS sensor, a low noise level amplifier, and a Σ - \triangle modulator.



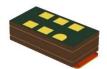
VDD GND

Fig. 1 Microphone block diagram

Key Features

- 4.0x2.0x1.1 mm Top Port
- 1-bit PDM Output \diamondsuit
- Narrow Sensitivity +/-1dBFS \diamond
- \diamondsuit High SNR of 64dBA
- \diamondsuit Flat Frequency Performance
- Multi Mode(Sleep,Low power,Normal) \diamond
- Compatible with Standard SMD Reflow Technology \diamondsuit
- RoHSCompliance&Halogen Free

Top View



Bottom View

Typical Applications

- ♦ Mobilephones
- NotebookComputers
- ♦ Smart Speakers
- ♦ Wearable Electronics
- Digital Video Cameras
- ♦ Smart Home Electronics

Maximum Ratings

Stresses at the maximum ratings shown in Table 1 may cause permanent damage to the device. These are stress ratings only at which the device may not function when an operation at these or any other condition beyond those specified under "Electro-Acoustic Specifications".

Table 1 Maximum Ratings

Parameters	Maximum Ratings	Unit
Power supply voltage	6.5	V
Operation temperature range	-40~85	${\mathbb C}$
Storage temperature range	-40~125	\mathbb{C}



Electro-Acoustic Specifications

Table 2 Normal Mode Electrical Specifications

Test condition:+25±2°C,60% \sim 70% RH,86 \sim 106Kpa,F_{CLK}=2.4MHz,V_{DD}=1.8V,no load,unless otherwise noted.

Symbol	Description	Min.	Тур.	Max.	Units
F _{CLK}	Clock Frequency	1.3	2.4	4.8	MHz
I _{DD}	Supply Current ¹		770	900	uA
s	Sensitivity ³ ,94dB SPL@1KHz	-27	-26	-25	dBFS ²
ΔS	Sensitivity drop	-0.25		0.25	dBFS
SNR	20-20KHzBandwidth,A-weighted	62	64		dB(A)
THD	94dB SPL@1KHz		0.25	0.5	%
AOP	10%THD@1KHz	118	121		dBSPL
PSR+N	Measured with 217Hz,100mVpp square wave			-75	dBFS
PSRR	Measured with 1KHz,200mVpp sine wave	50			dBFS
Phase	100-10KHz		±5	I	degree

Table 3 Low Power Mode Electrical Specifications

Test condition:+25±2°C, 60% \sim 70% RH, 86 \sim 106Kpa,F_{CLK}=768KHz,V_{DD}=1.8V,no load, unless otherwise noted.

Symbol	Description	Min.	Тур.	Max.	Units
Fclk	Clock Frequency	150	768	900	KHz
I _{DD}	Supply Current		330	500	uA
S	Sensitivity,94dB SPL@1KHz	-27	-26	-25	dBFS
ΔS	Sensitivity drop	-0.25		0.25	dBFS
SNR	20Hz~8KHz Bandwidth, A-weighted		64		dB(A)
THD	94dB SPL@1KHz		0.25	0.5	%
AOP	10%THD@1KHz	118	121		dBSPL
PSR+N	Measured with 217Hz,100mV _{pp} square wave			-75	dBFS
PSRR	Measured with 1KHz,200mVpp sine wave	50			dBFS
Phase	100-6KHz		±5 degre		

- Note 1:The current consumption depends on the applied clock frequency and the load on the DATA output
- Note 2:dBFS=20*logA/B,where A is the level of signal, and B is the level that corresponds to full-scale level
- Note 3:Relative to the rms level of a sine wave with positive amplitude equal to 100%1s density and negative amplitude equal to 0%1sdensity
- Note 4: Frequency response, sensitivity and current consumption are tested by 100% on product line.



Table 4 General Electrical Specifications

Test condition: $+25\pm2^{\circ}$ C, $60\%\sim70\%$ RH, $86\sim106$ Kpa,no load, unless otherwise noted.

Symbol	Description		Min.	Тур.	Max.	Units
V _{DD}	Supply Voltage		1.62	1.8	3.6	< >
ISLEEP	Power Consumption of	Stand By		3	50	uA
		Standby Mode	0		10	KHz
Fclk	Clock Frequency	Low Power Mode	150	768	900	KHz
		Normal Mode	1.3	2.4	4.8	MHz
Data Format	·		1/2 Cyc	le PDM		
Directivity			Omni-di	rectional		
Polarity	Increasing sound pressure		Increasing density of 1's			
Isc	Short circuit current Gr	ounded DATA	1		20	mA
CLOAD	Load capacitance				100	pF
Reset time	Time to start up in any mode after VDD has been off for more than10ms, while CLOCK remained on				20	ms
Start-up time	Start-up into normal mode or LP mode				20	ms
Mode-switch time	Mode-switch Normal m mode to Normal mode	node to LP mode or LP			20	ms

Table 5 Digital input—output specifications

Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Clock duty cycle		40	50	60	%	
Operation Voltage	V _{DD}	1.62		3.6	V	
Input Logic Low Level	V _{IL}	-0.3		0.35×V _{DD}	V	
Input Logic High Level	V _{IH}	0.65×V _{DD}		V _{DD} +0.3	V	
Output Logic Low Level	V _{OL}			0.45	V	
Output Logic High Level	V _{OH}	V _{DD} -0.45			V	
Clock rise time	t _{CR}			6	ns	35%~65%
Clock fall time	t _{CF}			6	ns	65%~35%
Delay time for data valid	t _{DV}	40		100	ns	Delay time from clock edge(0.50 x VDD) to data valid(<v<sub>OL or > V_{OH})</v<sub>



Delay time for data driven	t _{DD}	25	50	ns	Delay time from clock edge (50% VDD) to data driven.
Delay time for data high Z	t _{Hz}	5	20	ns	Delay time from clock edge(50% VDD) to data high impedance state

Table 6 L/R Channel Configuration

Channel	L/R pad connection	DATA driven	Data high Z
DATA1	GND	CLK falling edge	CLK rising edge
DATA2	VDD	CLK rising edge	CLK falling edge

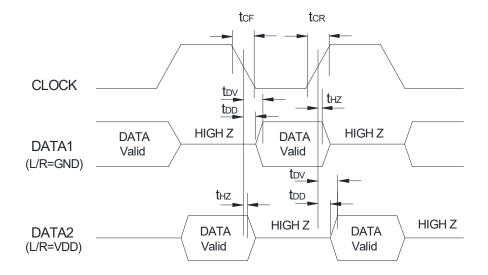


Fig. 2 Recommended timing diagram

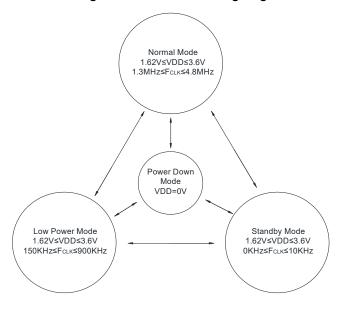
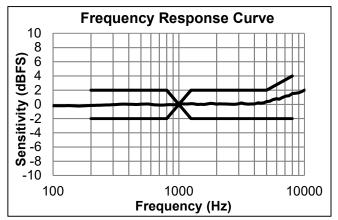


Fig. 3 State diagram



Performance Curves

All curves are tested under1.8V,2.4MHz unless otherwise noted.



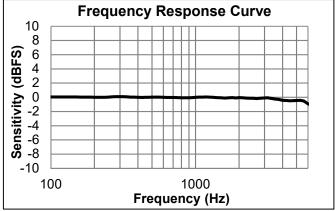
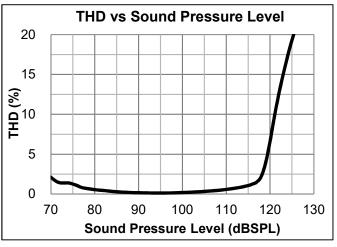


Fig. 4 Normal mode FR normalized to 1KHz

Fig. 5 Low power mode FR normalized to 1KHz



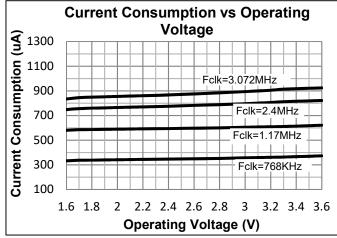
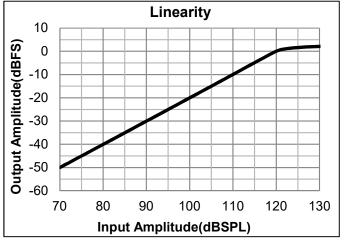


Fig. 6 Typical THD vs Sound Pressure Level

Fig. 7 Typical Current Consumption curve



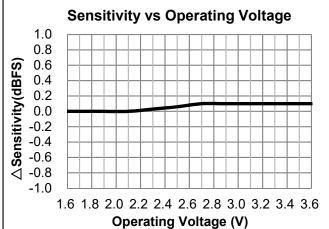


Fig. 8 Linearity

Fig. 9 Sensitivity vs Operating Voltage



Measurement System Setup

Test signal: Sinusoid, Sweep,

Step: 1/12 octave

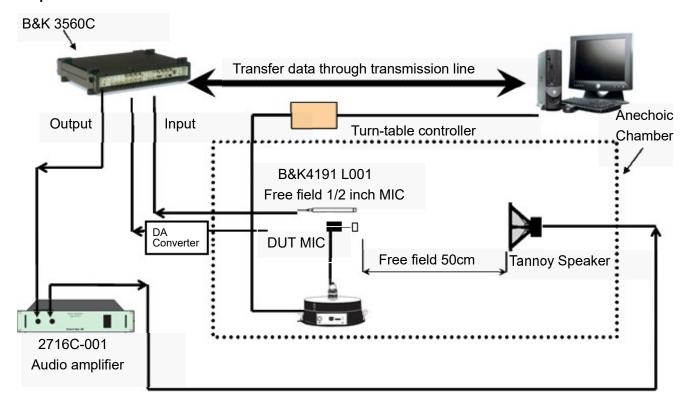


Fig. 10 Measurement System Setup



Typical Application Circuit

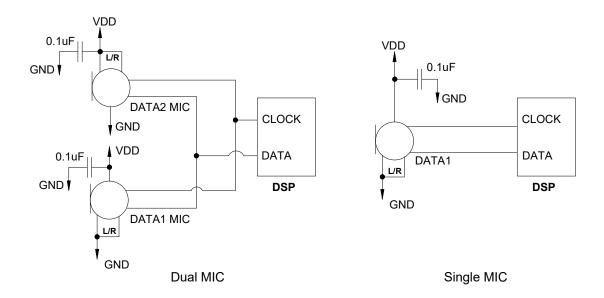


Fig. 11 Typical Application Circuit

Note1:L/R must be connected to VDD or GND even single MIC use.

Note2:A 0.1uF ceramic type decoupling capacitor strongly recommended for every microphone and it should be placed as close to the VDD pad to reduce the noise on power supply;

The trace connected to each pad of capacitor should be as short as possible, and should stay on one layer of PCB without via. For the best performance, recommend to place the capacitor equidistance from power and ground pins of microphone, or slightly closer to the power pin if space not allowed. System ground should connect to far side of the capacitor, as shown in fig. 12.

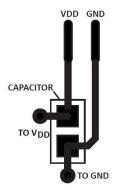


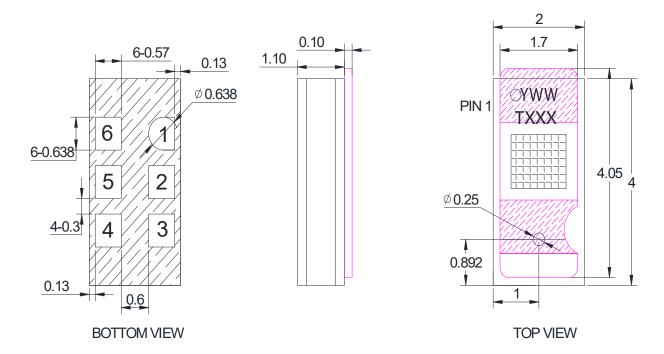
Fig. 12 Recommended Power Supply Decoupling Capacitor Layout

Note3: Do not use a pull-up or pull-down resistor on the PDM data signal line, because it can pull the signal to an incorrect state during the period that the signal line is restarted.

Note3: When long wire is used to connect the CLK of codec and microphone, a $50\sim100\Omega$ resistor should be placed near the codec to reduce signal over-shoot or ringing.



Mechanical Specifications



Unit: mm Unmarked Tolerance: ± 0.1

Fig. 9 Dimension

Item	Dimension	Tolerance
Length	4.0	±0.1
Width	2.0	±0.1
Height	1.1	±0.1
Acoustic Port	0.25	±0.05

PIN	Definition	Description	
1	VDD	Power Supply	
2	GND	Ground	
3	DATA	PDM output	
4	CLK	Clock input	
5	GND	Ground	
6	L/R	L/R select (No internal pull-down. Must be connected to VDD or GND)	

Note:

- All Ground Pin must be connected to the ground in end application
- The L/R pin is suggested to connect to GND during single mic application.
- Identification Marking
 - o: Polarity sign Y: Year WW: Week
 - T: GETTOP XXX: Serial Number
 - 2D Barcode



Reliability Specifications

After conducting any of the following tests, the sensitivity change of DUT shall be less than±3dBFS from its initial value unless otherwise noted,and shall keep its initial operation and appearance.

Table 7 Electrical Specifications

No.	Item	Test condition
110.	TOTAL STATE OF THE	
		24 hour bake at 125°C, followed by 168 hours at 85°C, 85%RH,
		followed by 3 passes solder reflow
1	Preconditioning	only for the following three tests:
		High Humidity &High Heat operating Test
		High Humidity &High Heat operating Test
	10.7	Thermal Shocking Test
2	Hi-Temperature Storage Test	105±3°C,1000h,recover for two hours
3	Hi-Temperature operating Test	105±3℃, under upper limit bias,1000h,recover for two hours
4	Low-Temperature storage Test	-40±3℃,1000h, recover for two hours
5	Low-Temperature operating Test	-40±3℃, under upper limit bias,1000h,recover for two hours
	High Humidity &High Heat	85±3℃, 85%RH, under upper limit bias, 1000h,recover for two
6	operating Test	hours, there should be no corrosion and deformation inside of
	operating rest	microphone after testing
	High Humidity &High Heat	65±3℃, 95%RH, under upper limit bias, 168h,recover for two
7	operating Test	hours ,there should be no corrosion and deformation inside of
	speciality rest	microphone after testing
8	Thermal Shocking Test	Double-Case Method, -40°C for 15mins→125°C for 15 mins, 100
		cycles, recover for two hours
9	Vibration Test	Each 12mins for X, Y and Z axes, Frequency: 20~2000Hz,
		Peak Acceleration 20g, recover for two hours
		Height:1.5m
		Fixture Weight: 150g
10	Drop Test	(Sound Hole Diameter in the fixture is >=0.8mm)
		Reference Surface:slippery marble floor
		Duration:4 corners*4 times, 6 faces*4 times
		The sensitivity change should be less than 1dB after testing
		Height: 1.0m
		Fixture Weight: 150g (Sound Hole Diameter in the fixture is >=0.9mm)
11	Tumbling Test	(Sound Hole Diameter in the fixture is >=0.8mm) Duration: 300 times
		The sensitivity change should be less than 1dB after testing



B				
12	ESD Test 1	a. HMB Discharge Position: Charge Voltage: Discharge Network: b. CDM Discharge Position: Charge Voltage:	I/O pins ±3000V 100pF & 1500Ω I/O pins ±250V	
13	ESD Test 2	The tests are performed acc. to IEC61000-4-2 level 3: a. Contact Discharge Discharge Position: Output of Microphone Charge Voltage:±6000VDC Discharge Network:150pF & 330Ω b. Air Discharge Discharge Position:Sound Hole Charge Voltage:±8000VDC Discharge Network:150pF & 330Ω		
14	Structure Shock Test	10000g, Duration: 0.1ms, each 3 shocks for X/Y/Z 3 axes, The sensitivity change should be less than 1dB after testing		
15	Reflow	3 reflow cycles with peak temperature of +260 ℃ according to reflow profile		



Packaging Details

- * Use ESD reel and tape for microphone packaging.
- * Anti-static measures should be applied during packaging operation.

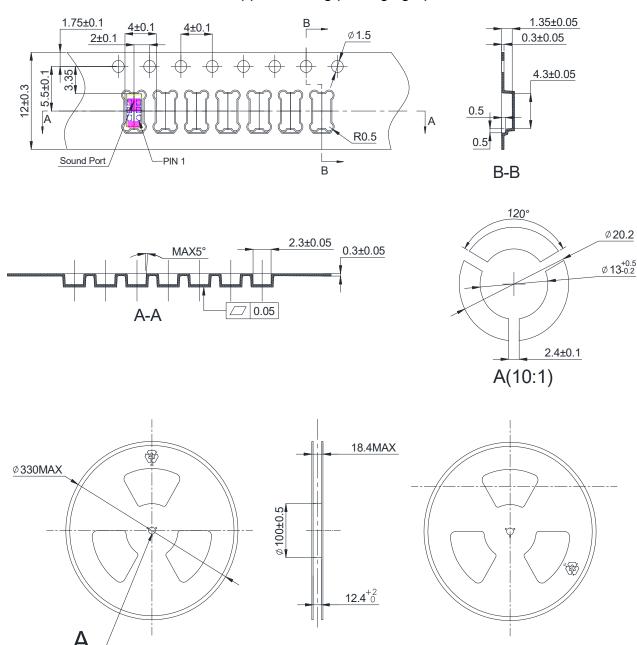
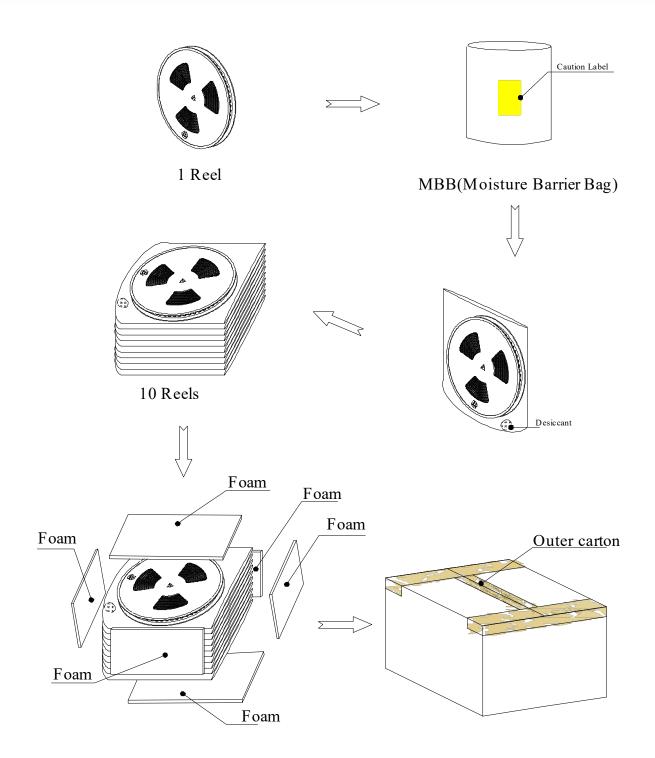


Fig. 13 Packaging



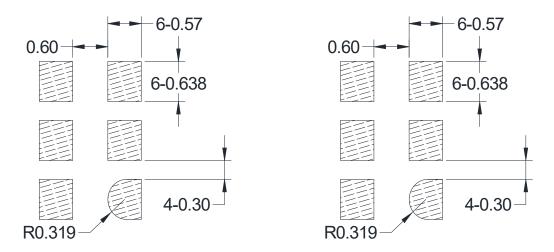


Tape and Reel	φ330mm	10,000PCS×1=10,000PCS
Shipping Box	390mm*390mm*235mm	10,000PCS×10=100,000PCS



Application Design Suggestions

Recommended PCB and Stencil Design Pattern



Example Land Pattern Example Solder Stencil Pattern

Notes:

- Dimensions are in millimeters unless otherwise specified.
- Tolerance is ± 0.1 mm unless otherwise specified.

Temperature Profile during Reflow Process

Table 8 Temperature Profile during Reflow Process

Parameter		Reference	Specification
Average Ramp Rate		T _L to T _P	3°C/sec max
Preheat	Minimum Temperature	T _{SMIN}	150°C
	Maximum Temperature	T _{SMAX}	200°C
	Time T _{SMIN} to T _{SMAX}	ts	60 sec to 180 sec
Ramp-Up Rate		T _{SMAX} to T _L	1.25°C/sec
Time Maintained Above Liquidous		t _L	60 sec to 150 sec
Liquidous Temperature		TL	217°C
Peak Temperature		ТР	260°C
Time Within +5°C of Actual Peak Temperature		t _P	20 sec to 40 sec
Ramp-Down Rate		T _P to T _{SMAX}	6°C/sec max
Time +25°C (t25°C) to Peak Temperature			8 min max

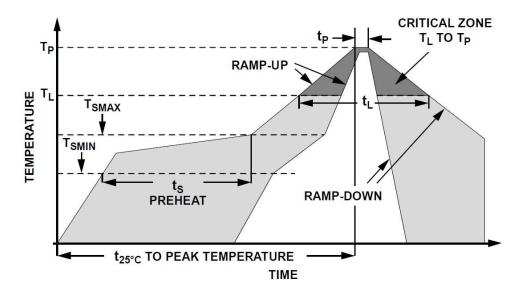


Fig. 14 Reflow Profile

Additional Notes:

- Mic should cool to room temp before next flow cycle if more reflow is needed.
- No more than 3 times reflow is recommended.
- Do not board wash by liquid or ultrasonic after the reflow process.
- Do not pull a vacuum over port hole of the microphone.
- Do not insert any object in port hole of device at any time.
- Suggest SMT the microphone at last time if double side PCBA used.
- Do not seal sound port during reflow .
- If there is any leakage risk, the peak temperature should be set to less than 240°C or more than 255°C.



Recommended Nozzle for Reflow MIC

External diameter is Φ1.8mm Inside diameter is Φ1.2mm

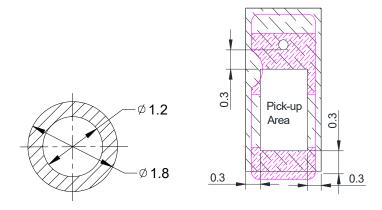


Fig. 15 Recommended nozzle for reflow MIC and Pick-up Area

Special Cautions

Air Rifle Cleaning Restriction

Do not bring air rifle to the port hole directly.

Recommended Condition:

Air pressure < 0.3MPa;

Distance>5cm;

Time<5sec.

Package

Do NOT vacuum seal unused material for storage. Vacuum Sealing can cause mic damage.

Storage

The component needs to meet the requirement of MSL(Moisture Sensitivity Level) class 1. Please keep MICs in warehouse with humidity less than 75% and without sudden temperature change, acid air, and any other harmful air or strong magnetic field.

Please protect products against moist, shock, sunburn and pressure.

Please take proper measures against ESD in the process of assembly and transportation. Please use the shipping package for long-term storage.

Discard

For microphones to be wasted, customer shall follow the regulation of Waste Electrical and Electronic Equipment (WEEE) Directive (2002/96/EC).

Notes: More application suggestions can be found in the latest "MEMS Microphone Application Notes".



Specification Revisions

Date	Version	Description
06-28-2022	V1.0	Preliminary
06-29-2022	V2.0	Updated SNR and frequency response performance
07-19-2022	V3.0	Updated electro-acoustic performance
08-29-2022	V4.0	Updated product name, normal mode PSRR, marking and performance curves
10-24-2022	V5.0	Updated timing specification and packaging details
12-14-2022	V6.0	Updated marking information and clock rise and fall time
05-18-2023	V7.0	Updated reflow specification
12-27-2023	V8.0	Updated power consumption of standby mode
03-28-2024	V9.0	Updated packaging details
04-03-2025	V10.0	Updated packaging details